NSN 5961-00-854-7149

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-854-7149 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 3.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead **Specification Data:** 80131-release3012 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No